IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

(IBMF-0058)

Applicant: William G. America Conf. No.: 3775

Serial No.: 10/709,776 **Art Unit**: 2811

Filed: 05/27/2004 Examiner: Im, Junghwa M.

Title: SEMICONDUCTOR DEVICE FORMED Docket No.: FIS920040083US1

BY IN-SITU MODIFICATION OF

DIELECTRIC LAYER AND RELATED

METHODS

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

REQUEST FOR RECONSIDERATION

Sir:

I. INTRODUCTORY COMMENTS

This paper is being filed in response to the Office Action dated September 12, 2007.

Please reconsider the above-referenced patent application as follows: